

**Electronic Patent Application Fee Transmittal**

<b>Application Number:</b>	10589680			
<b>Filing Date:</b>	16-Aug-2006			
<b>Title of Invention:</b>	Silicon Carbide Single Crystal, Silicon Carbide Single Crystal Wafer, and Method of Production of Same			
<b>First Named Inventor/Applicant Name:</b>	Masashi Nakabayashi			
<b>Filer:</b>	Aaron Grunberger/Katy Chan-Parsons			
<b>Attorney Docket Number:</b>	52433/858			
Filed as Large Entity				
<b>U.S. National Stage under 35 USC 371 Filing Fees</b>				
<b>Description</b>	<b>Fee Code</b>	<b>Quantity</b>	<b>Amount</b>	<b>Sub-Total in USD(\$)</b>
<b>Basic Filing:</b>				
<b>Pages:</b>				
<b>Claims:</b>				
Claims in excess of 20	1615	2	52	104
<b>Miscellaneous-Filing:</b>				
<b>Petition:</b>				
<b>Patent-Appeals-and-Interference:</b>				
<b>Post-Allowance-and-Post-Issuance:</b>				
<b>Extension-of-Time:</b>				

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Miscellaneous:				
Total in USD (\$)				104